

KSC2316

Audio Power Amplifier Applications

- Driver Stage Amplifier
- Complement to KSA916



1. Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage	120	V
V _{CEO}	Collector-Emitter Voltage	120	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	800	mA
P _C	Collector Power Dissipation	900	mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ +150	°C

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C=1mA$, $I_E=0$	120			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =10mA, I _B =0	120			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =1mA, I _C =0	5			V
I _{CBO}	Collector Cut-off Current	V _{CB} =120V, I _E =0			0.1	μΑ
h _{FE1}	DC Current Gain	V _{CE} =5V, I _C =10mA	60			
h _{FE2}		V_{CE} =5V, I_{C} =100mA	80		240	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =500mA, I _B =50mA			1	V
f _T	Current Gain Bandwidth Product	V _{CE} =5V, I _C =100mA		120		MHz
C _{ob}	Collector Output Capacitance	V _{CB} =10V,I _E =0, f=1MHz			30	pF

h_{FE} Classification

Classification	0	Υ
h _{FE2}	80-160	120-240

Typical Characteristics

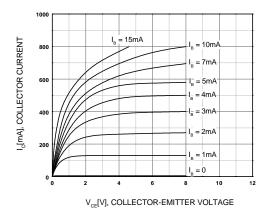


Figure 1. Static Characteristic

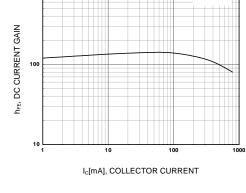


Figure 2. DC current Gain

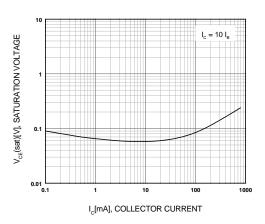


Figure 3. Collector-Emitter Saturation Voltage

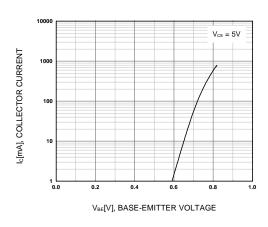


Figure 4. Base-Emitter On Voltage

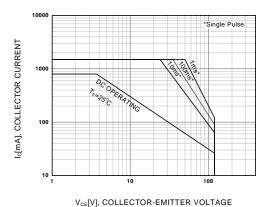


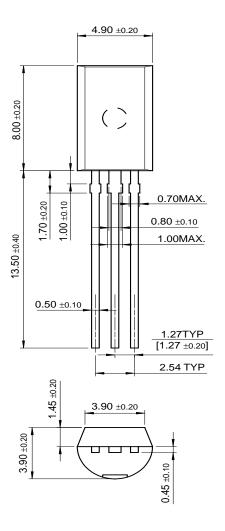
Figure 5. Safe Operating Area

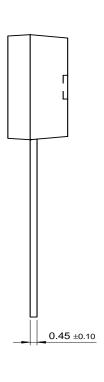
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